

# GaAs High Isolation Switch DC - 3.0 GHz

Rev. V4

#### **Features**

- Low Power Consumption: < 15 μA @ +2.5V
- High Isolation: 50 dB Typical @ 2 GHz
- Low Insertion Loss: 0.7 dB @ 2 GHz
- Positive 2.5 to 5 V Control
- Low Cost Plastic MSOP-10 Package

#### **Description**

The SW-439 is a GaAs MMIC SPDT switch in a low cost MSOP-10 surface mount plastic package. This part is ideal for high isolation, broadband switching requirements. Typical applications include synthesizer switching, transmit/receive switching, switch matrices and filter banks in systems such as radio and cellular equipment, PCM, GPS, and fiber optic modules.

The SW-439 is fabricated as a monolithic GaAs MMIC using a 0.5 micron pHEMT process. The process features full passivation.

# Ordering Information<sup>1</sup>

Part Number	Package		
SW-439	Bulk Packaging		
SW-439TR	1000 piece reel		
SW-439SMB	Sample Board		

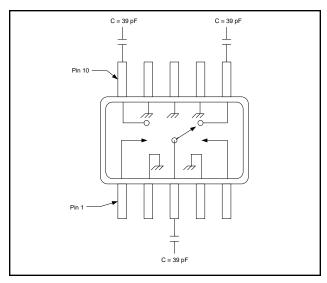
1. Reference Application Note M513 for reel size information.

# Absolute Maximum Ratings <sup>2,3</sup>

Parameter	Absolute Maximum		
Input Power	+30 dBm		
Operating Voltage	+8.5 Volts		
Operating Temperature	-40°C to +85°C		
Storage Temperature	-65°C to +150°C		

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.

## Functional Schematic 4



For improved performance at frequencies below 500 MHz, use larger value capacitors.

### **Pin Configuration**

Pin No.	Function	Pin No.	Function	
1	Control 1	6	RF Port 2	
2	Ground	7	Ground	
3	RF Input	8	Ground	
4	Ground	9	Ground	
5	Control 2	10	RF Port 1	

## Truth Table 5,6

Control V1	Control V2	RFC - RF1	RFC - RF2
0	1	Off	On
1	0	On	Off

- 5. External DC blocking capacitors are required on all RF ports.
- 6. "0" = 0 + 0.2 Vdc, "1" = +2.5 to +5 Vdc

<sup>•</sup> Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
Visit www.macomtech.com for additional data sheets and product information.



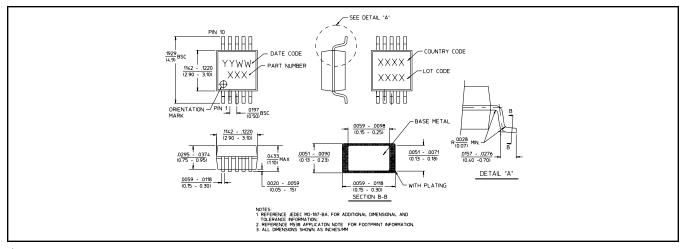
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# Electrical Specifications: $T_A = 25$ °C, $V_C = 0 / 3 V$ , $Z_0 = 50 \Omega$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Insertion Loss	DC - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz	dB dB dB		0.55 0.65 0.80	0.65 0.75 0.90
Isolation	DC - 2.0 GHz 2.0 - 3.0 GHz	dB dB	45 31	47 33	_
VSWR	0.25 - 3.0 GHz	Ratio	_	1.2:1	1.3:1
P1dB	500 MHz - 2.0 GHz, V <sub>C</sub> = 2.5 V	dBm	_	20	_
P1dB	500 MHz - 2.0 GHz, $V_C = 5 \text{ V}$	dBm	_	28	_
IP2	2 Tone, 900 MHz, 5 MHz Spacing, $V_C = 3 \text{ V}$	dBm	_	85	_
IP3	2 Tone, 900 MHz, 5 MHz Spacing, $V_C = 3 \text{ V}$	dBm	_	50	_
Ton, Toff	50% Control to 90% RF, 50% Control to 10% RF	nS	_	20	_
Trise, Tfall	10% to 90% RF, 90% to 10% RF	nS	_	10	_
Transients	In-band	mV	_	15	_
Control Current	V <sub>C</sub>   = 2.5 V	μA	_	5	15

### MSOP-10<sup>†</sup>



Meets JEDEC moisture sensitivity level 1 requirements. Plating is 100% matte tin over copper.

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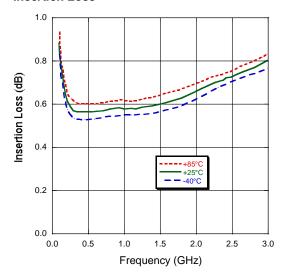


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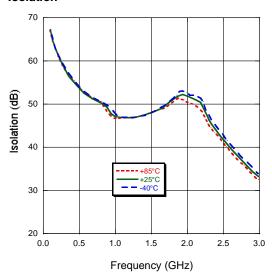
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## **Typical Performance Curves**

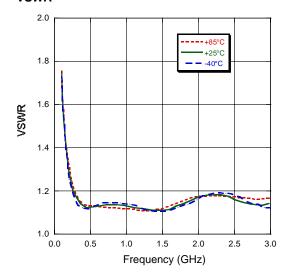
#### Insertion Loss



#### Isolation



#### **VSWR**



## **Handling Procedures**

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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